



High Speed Infrared Emitting Diode, 890 nm, GaAlAs, DH



DESCRIPTION

VSMF2893SLX01 is an infrared, 890 nm, side looking emitting diode in GaAlAs (DH) technology with high radiant power and high speed, molded in clear, untinted plastic package (with lens) for surface mounting (SMD).

FEATURES

- Package type: surface-mount
- Package form: side view
- Dimensions (L x W x H in mm): 2.3 x 2.55 x 2.3
- AEC-Q101 qualified
- Peak wavelength: $\lambda_p = 890$ nm
- High reliability
- High radiant power
- High radiant intensity
- Angle of half intensity: $\phi = \pm 25^\circ$
- Low forward voltage
- Suitable for high pulse current operation
- Package matches with detector VEMD2xx3SSLX01 and VEMT2xx3SLX01 series
- Floor life: 4 weeks, MSL 2a, acc. J-STD-020
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- IrDA compatible data transmission
- 3D TV
- IR touch panels
- Miniature light barrier
- Photointerrupters
- Optical switch
- Shaft encoders
- IR emitter source for proximity applications

PRODUCT SUMMARY

COMPONENT	I_e (mW/sr)	ϕ (deg)	λ_p (nm)	t_r (ns)
VSMF2893SLX01	20	± 25	890	30

Note

- Test conditions see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VSMF2893SLX01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	Side view

Note

- MOQ: minimum order quantity



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	5	V
Forward current		I_F	100	mA
Peak forward current	$t_p/T = 0.5$, $t_p = 100\text{ }\mu\text{s}$	I_{FM}	200	mA
Surge forward current	$t_p = 100\text{ }\mu\text{s}$	I_{FSM}	1	A
Power dissipation		P_V	160	mW
Junction temperature		T_j	100	$^{\circ}\text{C}$
Operating temperature range		T_{amb}	- 40 to + 85	$^{\circ}\text{C}$
Storage temperature range		T_{stg}	- 40 to + 100	$^{\circ}\text{C}$
Soldering temperature	Acc. figure 9, J-STD-020	T_{sd}	260	$^{\circ}\text{C}$
Thermal resistance junction/ambient	J-STD-051, leads 7 mm, soldered on PCB	R_{thJA}	250	K/W

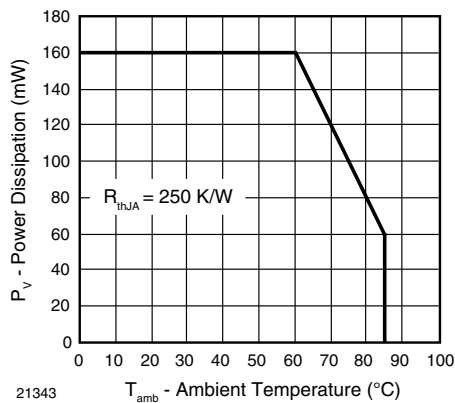


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

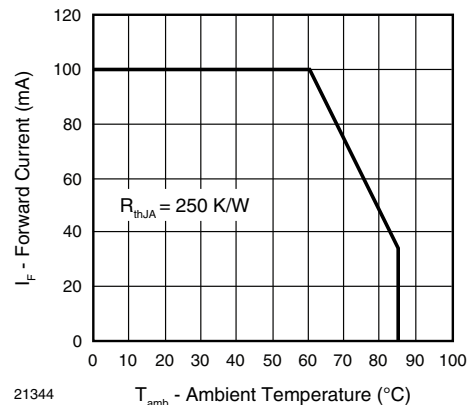


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$	V_F	1.25	1.4	1.6	V
	$I_F = 1\text{ A}$, $t_p = 100\text{ }\mu\text{s}$	V_F		2.3		V
Temperature coefficient of V_F	$I_F = 1\text{ mA}$	TK_{V_F}		- 1.8		mV/K
	$I_F = 100\text{ mA}$	TK_{V_F}		- 1.1		mV/K
Reverse current	$V_R = 5\text{ V}$	I_R			10	μA
Junction capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0\text{ mW/cm}^2$	C_J		125		pF
Radiant intensity	$I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$	I_e	10	20	30	mW/sr
	$I_F = 1\text{ A}$, $t_p = 100\text{ }\mu\text{s}$	I_e		180		mW/sr
Radiant power	$I_F = 100\text{ mA}$, $t_p = 20\text{ ms}$	ϕ_e		40		mW
Temperature coefficient of ϕ_e	$I_F = 100\text{ mA}$	TK_{ϕ_e}		- 0.35		%/K
Angle of half intensity		ϕ		± 25		deg
Peak wavelength	$I_F = 30\text{ mA}$	λ_p	870	890	910	nm
Spectral bandwidth	$I_F = 30\text{ mA}$	$\Delta\lambda$		40		nm
Temperature coefficient of λ_p	$I_F = 30\text{ mA}$	TK_{λ_p}		0.25		nm/K
Rise time	$I_F = 100\text{ mA}$, 20 % to 80 %	t_r		30		ns
Fall time	$I_F = 100\text{ mA}$, 20 % to 80 %	t_f		30		ns
Cut-off frequency	$I_{DC} = 70\text{ mA}$, $I_{AC} = 30\text{ mA pp}$	f_c		12		MHz



BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

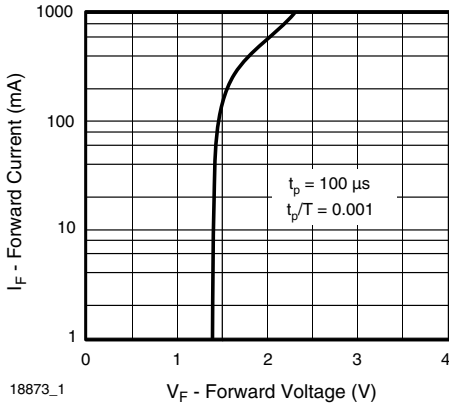


Fig. 3 - Forward Current vs. Forward Voltage

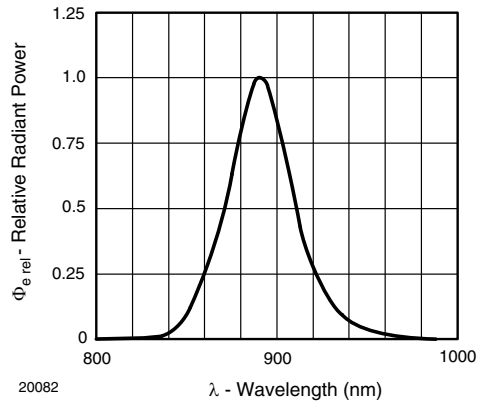


Fig. 6 - Relative Radiant Power vs. Wavelength

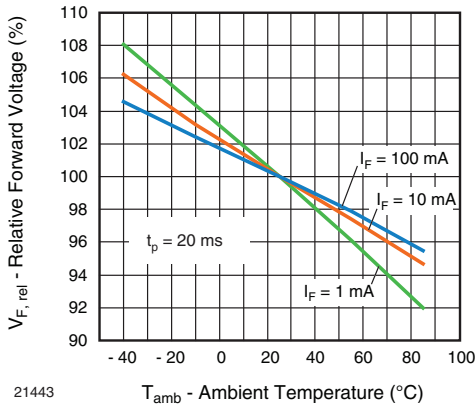


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

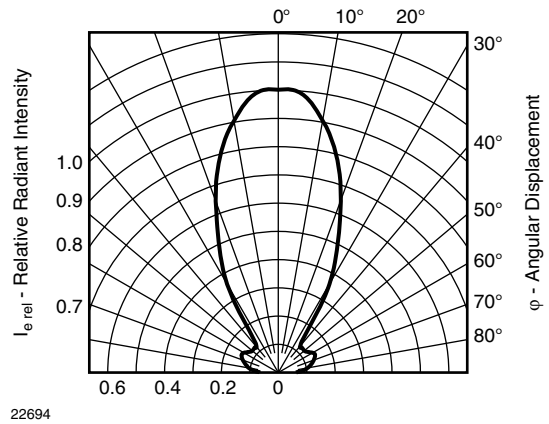


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

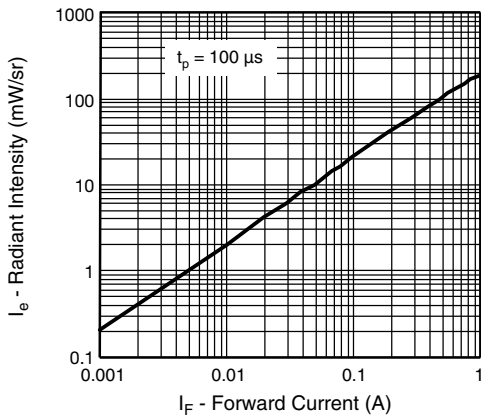


Fig. 5 - Radiant Intensity vs. Forward Current

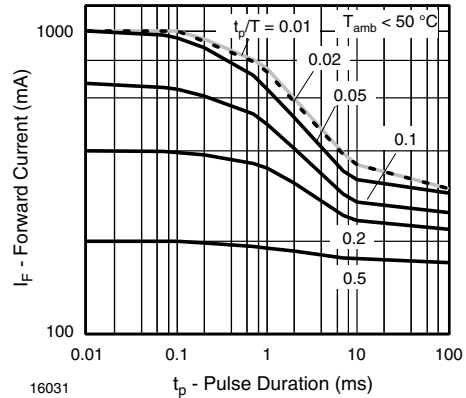


Fig. 8 - Pulse Forward Current vs. Pulse Duration

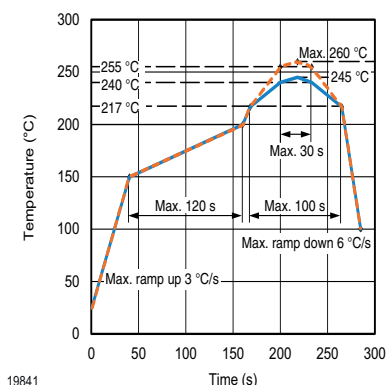
**SOLDER PROFILE**

Fig. 9 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions: $T_{amb} < 30\text{ }^{\circ}\text{C}$, RH < 60 %

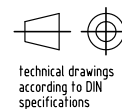
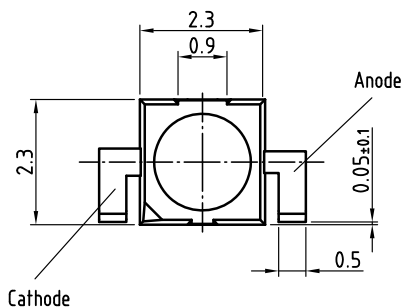
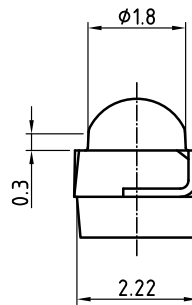
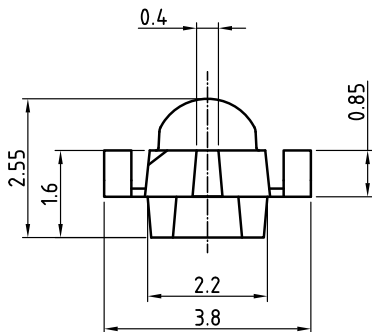
Moisture sensitivity level 2a, acc. to J-STD-020.

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

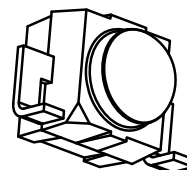
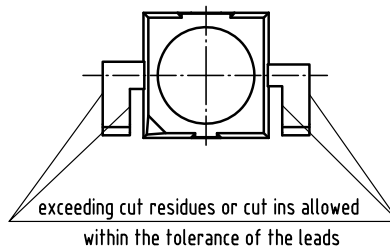
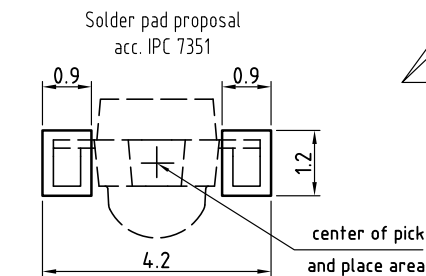


PACKAGE DIMENSIONS in millimeters: **VSMF2893SLX01**



technical drawings according to DIN specifications

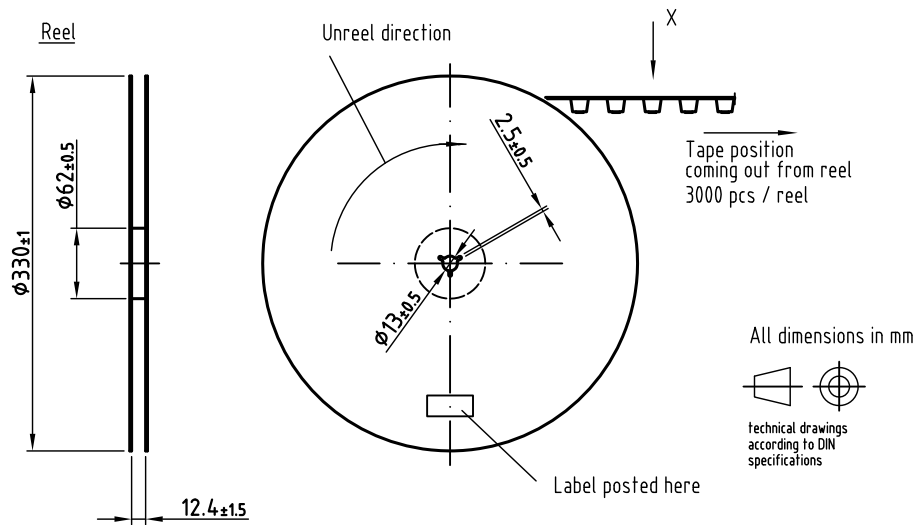
Dimensions in mm
Not indicated tolerances ±0.2



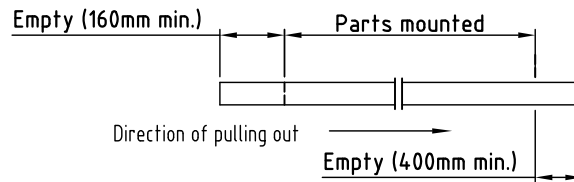
Drawing refers to following types: VSMB2943SLX01
VSMF2893SLX01
Drawing-No.: 6.544-5410.02-4 VSMB2948SL
Issue: prel. 03.08.12 VEMD2x23SLX01



TAPING AND REEL DIMENSIONS in millimeters: **VSMF2893SLX01**

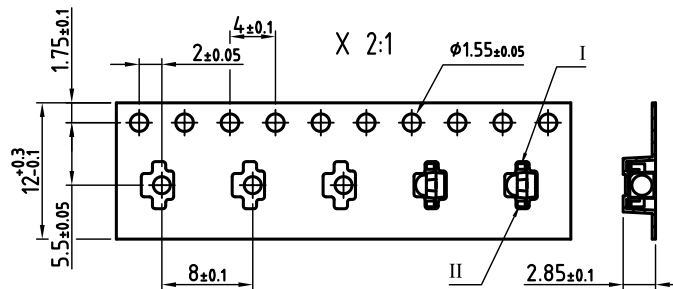


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II
V SMB294.3SLX01	Cathode	Anode
V SMF2893SLX01		
V SMB294.8SL		
V EMD2023SLX01		
V EMD2523SLX01	Collector	Emitter
V EMT2023SLX01		
V EMT2523SLX01	Anode	Cathode
V SMY2853SL		



Drawing refers to following types: see table
Reel dimensions and tape

Drawing-No.: 9.800-5123.01-4
Issue: prel; 01.02.13



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Infrared Emitters - High Power](#) category:

Click to view products by [Vishay](#) manufacturer:

Other Similar products are found below :

[TSHA6201](#) [TSHA6202](#) [SFH 4030](#) [SFH 4060](#) [SFH 4775S A01](#) [SFH 4726AS](#) [SFH 4725AS](#) [VSMY2853SLX01](#) [VSMY2853RGX01](#)
[VSMY2853GX01](#) [VSMY2850GX01](#) [IN-P281ASGHIR](#) [IN-P281ASGIR](#) [VSMY2890GX01](#) [VSMY2890RGX01](#) [SFH 4728AS A01](#) [SST-10-
IRD-B130H-S940](#) [SST-10-IRD-B50H-S940](#) [QEE123](#) [TSHA6200](#) [TSML1030](#) [VTE1291W-2H](#) [LL-304IRC4B-2AD](#) [LL-503HIRT2E-1CC](#)
[LL-503IRC2E-2AC](#) [LL-503IRC2V-2AD](#) [LL-503IRT2E-2AC](#) [LL-503IRT2E-2AE](#) [LL-503SIRC2E-1BD](#) [LL-S170IRC-2A](#) [SFH 4259](#)
[OS5RKAZ5D1P](#) [OSB56LZE31D](#) [OSG58AZ5D1P](#) [OSI3CA5111A](#) [OSI3NAS1C1A](#) [OSI5LA56A1A](#) [OSI5XNE3E1E](#) [OSIXCA5121A](#)
[OSIXCAS1C1A](#) [OSM54LZ5D1P](#) [OSM5D3Z2C1P](#) [OSMR43Z2C1P](#) [OSO5PAZ161D](#) [OSOR7161D](#) [OSPW7161D](#) [OSPW71B1P](#)
[OSR5PAZE31D](#) [OSR9XAE3E1E](#) [OSRICA3131A](#)